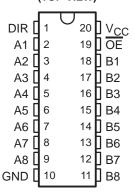
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- Outputs Have Equivalent 25- $\Omega$  Series Resistors, So No External Resistors Are Required
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- **High-Impedance State During Power Up** and Power Down
- Latch-Up Performance Exceeds 500 mA Per **JEDEC Standard JESD-17**
- ESD Protection Exceeds 2000 V Per MIL-STD-833, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 1 V at  $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Thin Very Small-Outline (DGV) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

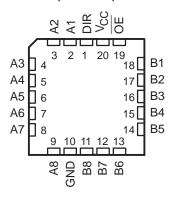
### description

These octal transceivers and line drivers are designed for asynchronous communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so the buses are effectively isolated.

SN54ABTR2245...J PACKAGE SN74ABTR2245...DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54ABTR2245 . . . FK PACKAGE (TOP VIEW)



Both the A-port and B-port outputs, which are designed to sink up to 12 mA, include equivalent 25- $\Omega$  series resistors to reduce overshoot and undershoot.

When  $V_{CC}$  is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABTR2245 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ABTR2245 is characterized for operation from -40°C to 85°C.

#### **FUNCTION TABLE**

INP	UTS	OPERATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

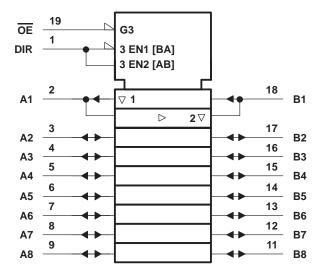


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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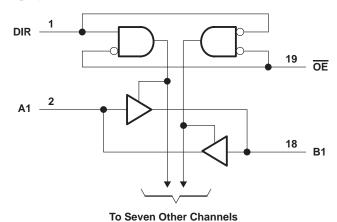
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### logic symbol†



 $<sup>\</sup>ensuremath{^{\dagger}}$  This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

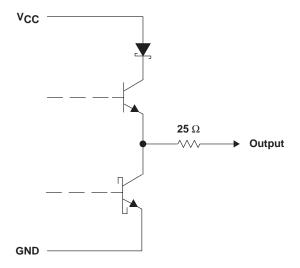
# logic diagram (positive logic)



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### output schematic



All resistor values shown are nominal.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		0.5 V to 7 V
Input voltage range, VI (except I/O ports) (see I	Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high	or power-off state, VO	–0.5 V to 5.5 V
Current into any output in the low state, IO		30 mA
Input clamp current, $I_{IK}$ ( $V_I < 0$ )		–18 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		–50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2):	DB package	115°C/W
	DGV package	146°C/W
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T <sub>stg</sub>		–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

<sup>2.</sup> The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.

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### recommended operating conditions (see Note 3)

			SN54ABT	R2245	SN74AB1	R2245	UNIT
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2	3	2		V
V <sub>IL</sub>	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0 4	Vcc	0	VCC	V
IOH	High-level output current		1	-12		-12	mA
loL	Low-level output current		22	12		12	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	20/	5		5	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAD	AMETER	TEST CON	IDITIONS	T,	A = 25°C	;	SN54AB1	TR2245	SN74ABTR2245		UNIT
FAN	ANIETER	TEST CON	IDITIONS	MIN	TYP <sup>†</sup>	MAX	MIN	MAX	MIN	MAX	ONIT
VIK		$V_{CC} = 4.5 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2		-1.2		-1.2	V
		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -1 \text{ mA}$	3.35			3.3		3.35		
VOH		$V_{CC} = 5 V$ ,	$I_{OH} = -1 \text{ mA}$	3.85			3.8		3.85		V
VOH		V <sub>CC</sub> = 4.5 V	$I_{OH} = -3 \text{ mA}$				3		3.1		V
		VCC = 4.0 V	$I_{OH} = -12 \text{ mA}$	2.6					2.6		
VOL		V <sub>CC</sub> = 4.5 V	IOL = 8 mA			0.65		0.8		0.65	V
		VCC = 1.0 V	I <sub>OL</sub> = 12 mA			8.0				0.8	•
V <sub>hys</sub>					100						mV
1.	Control inputs	$V_{CC} = 0 \text{ to } 5.5 \text{ V, V}_{I}$	= V <sub>CC</sub> or GND			±1		±1		±1	μΑ
t <sub>I</sub>	A or B ports	$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$	/,			±20		±20		±20	μΑ
I <sub>OZH</sub> ‡		$\frac{\text{V}_{CC}}{\text{OE}} \ge 2.1 \text{ V to } 5.5 \text{ V}$	$V_{0} = 2.7 V_{0}$			10		10		10	μΑ
I <sub>OZL</sub> ‡		$\frac{V_{CC}}{OE} = 2.1 \text{ V to } 5.5 \text{ V}$	$V_{0} = 0.5 V_{0}$			-10	,	-10		-10	μΑ
IOZPU§	}	$\frac{\text{VCC}}{\text{OE}} = 0 \text{ to } 2.1 \text{ V, VC}$	) = 0.5 V to 2.7 V,			±50	300%	±50		±50	μΑ
IOZPD§	}	$\frac{\text{VCC}}{\text{OE}} = 2.1 \text{ V to 0, V}_{\text{O}}$	0 = 0.5  V to  2.7  V,			±50	Q'	±50		±50	μΑ
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ
ICEX		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 5.5 V	Outputs high			50		50		50	μΑ
Io¶		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.5 V	-25		-100	-25	-100	-25	-100	mA
		V <sub>CC</sub> = 5.5 V,	Outputs high		1	250		250		250	μΑ
Icc	A or B ports	$I_{O} = 0$ ,	Outputs low		24	32		32		32	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.5	250		250		250	μΑ
	V <sub>CC</sub> = 5.5 V, One input at 3		Outputs enabled			1.5		1.5		1.5	
∆l <sub>CC</sub> #	Data inputs ΔI <sub>CC</sub> #	Other inputs at VCC or GND	Outputs disabled			0.05		0.05		0.05	mA
	Control inputs	$V_{CC} = 5.5 \text{ V}$ , One in Other inputs at $V_{CC}$				1.5		1.5		1.5	
Ci		V <sub>I</sub> = 2.5 V or 0.5 V			3						pF
C <sub>io</sub>		$V_0 = 2.5 \text{ V or } 0.5 \text{ V}$			6						pF

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.



<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ .

<sup>&</sup>lt;sup>‡</sup> The parameters I<sub>OZH</sub> and I<sub>OZL</sub> include the input leakage current.

<sup>§</sup> This parameter is characterized but not production tested.

<sup>¶</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

<sup>#</sup>This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.

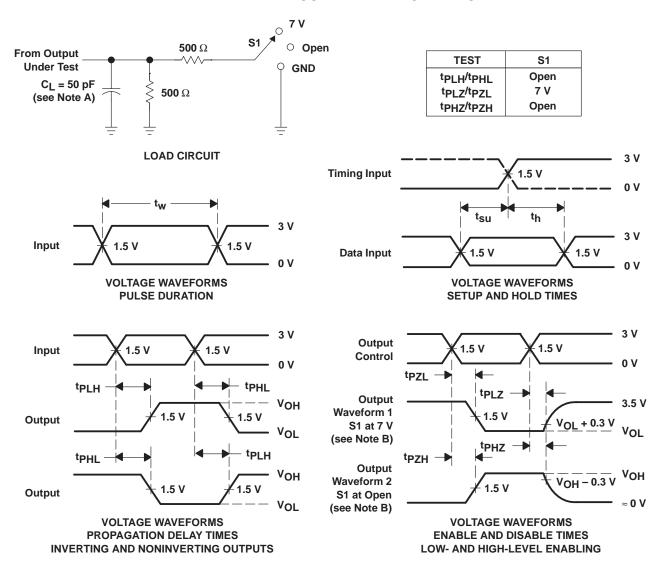
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switching characteristics over recommended ranges of supply voltage and operating free-air temperature,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO (INPUT) (OUTPUT)		V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C			R2245	SN74AB1	UNIT	
	(IIII O1)	(001101)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	1	2.5	3.4	1	4	1	3.8	no
tPHL	AUIB	D UI A	1	3.2	4.2	1 (	4.6	1	4.5	ns
<sup>t</sup> PZH	<del></del>	A or B	1.5	3.6	4.9	1.5	6.3	1.5	6.1	no
t <sub>PZL</sub>	ŌĒ	AUIB	1.5	3.9	5.3	1.5	6.6	1.5	6.3	ns
<sup>t</sup> PHZ	ŌĒ	A or P	1.5	3.6	4.7	1.5	5.5	1.5	5.3	ns
t <sub>PLZ</sub>	OE OE	A or B	1.5	3.3	4.4	1.5	4.9	1.5	4.8	

6

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O} = 50 \Omega$ ,  $t_{f} \leq$  2.5 ns,  $t_{f} \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74ABTR2245DW	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABTR2245
SN74ABTR2245DW.B	Active	Production	SOIC (DW)   20	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABTR2245
SN74ABTR2245DWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABTR2245
SN74ABTR2245DWR.B	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABTR2245
SN74ABTR2245PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AR245
SN74ABTR2245PWR.B	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AR245

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# **PACKAGE OPTION ADDENDUM**

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# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABTR2245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ABTR2245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABTR2245DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74ABTR2245PWR	TSSOP	PW	20	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ABTR2245DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74ABTR2245DW.B	DW	SOIC	20	25	507	12.83	5080	6.6



SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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